

Silicon Power Transistors

MJ15023 (PNP), MJ15025 (PNP)

The MJ15023 and MJ15025 are power transistors designed for high power audio, disk head positioners and other linear applications.

Features

- High Safe Operating Area
- High DC Current Gain
- Complementary to MJ15022 (NPN), MJ15024 (NPN)
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|----------------|-------------|--------------------------|
| Collector-Emitter Voltage MJ15023 MJ15025 | V_{CEO} | 200 250 | Vdc |
| Collector-Base Voltage MJ15023 MJ15025 | V_{CBO} | 350 400 | Vdc |
| Emitter-Base Voltage | V_{EBO} | 5 | Vdc |
| Collector-Emitter Voltage | V_{CEX} | 400 | Vdc |
| Collector Current – Continuous (Note 1) | I_C | 16 | Adc |
| Collector Current – Peak (Note 1) | I_{CM} | 30 | Adc |
| Base Current – Continuous | I_B | 5 | Adc |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | 250 1.43 | W W/ $^\circ\text{C}$ |
| Operating and Storage Junction Temperature Range | T_J, T_{stg} | -65 to +200 | $^\circ\text{C}$ |

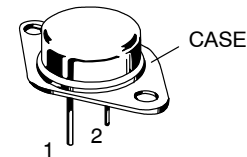
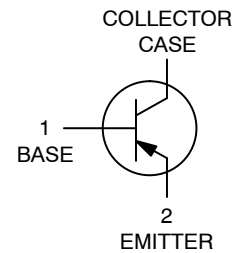
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Pulse Test: Pulse Width = 5 ms, Duty Cycle $\leq 10\%$.

THERMAL CHARACTERISTICS

| Characteristics | Symbol | Max | Unit |
|--------------------------------------|-----------------|------|--------------------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 0.70 | $^\circ\text{C/W}$ |

16 AMPERES SILICON POWER TRANSISTORS 200 – 250 VOLTS, 250 WATTS



TO-204 (TO-3)
CASE 1-07
STYLE 1

MARKING DIAGRAM



MJ1502x = Device Code
 x = 3 or 5
 G = Pb-Free Package
 A = Assembly Location
 Y = Year
 WW = Work Week
 MEX = Country of Origin

ORDERING INFORMATION

| Device | Package | Shipping |
|----------|---------------------|------------------|
| MJ15023G | TO-204 (Pb-Free) | 100 Units / Tray |
| MJ15025G | TO-204 (Pb-Free) | 100 Units / Tray |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the [onsemi Soldering and Mounting Techniques Reference Manual](#), SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|---|----------------|------------|------------|-----------------|
| OFF CHARACTERISTICS | | | | |
| Collector-Emitter Sustaining Voltage (Note 2) ($I_C = 100\text{ mAdc}$, $I_B = 0$) MJ15023 MJ15025 | $V_{CEO(sus)}$ | 200 250 | – – | – |
| Collector Cutoff Current ($V_{CE} = 200\text{ Vdc}$, $V_{BE(off)} = 1.5\text{ Vdc}$) MJ15023 ($V_{CE} = 250\text{ Vdc}$, $V_{BE(off)} = 1.5\text{ Vdc}$) MJ15025 | I_{CEX} | – – | 250 250 | μAdc |
| Collector Cutoff Current ($V_{CE} = 150\text{ Vdc}$, $I_B = 0$) MJ15023 ($V_{CE} = 200\text{ Vdc}$, $I_B = 0$) MJ15025 | I_{CEO} | – – | 500 500 | μAdc |
| Emitter Cutoff Current ($V_{CE} = 5\text{ Vdc}$, $I_B = 0$) Both | I_{EBO} | – | 500 | μAdc |
| SECOND BREAKDOWN | | | | |
| Second Breakdown Collector Current with Base Forward Biased ($V_{CE} = 50\text{ Vdc}$, $t = 0.5\text{ s}$ (non-repetitive)) ($V_{CE} = 80\text{ Vdc}$, $t = 0.5\text{ s}$ (non-repetitive)) | $I_{S/b}$ | 5 2 | – – | Adc |
| ON CHARACTERISTICS | | | | |
| DC Current Gain ($I_C = 8\text{ Adc}$, $V_{CE} = 4\text{ Vdc}$) ($I_C = 16\text{ Adc}$, $V_{CE} = 4\text{ Vdc}$) | h_{FE} | 15 5 | 60 – | – |
| Collector-Emitter Saturation Voltage ($I_C = 8\text{ Adc}$, $I_B = 0.8\text{ Adc}$) ($I_C = 16\text{ Adc}$, $I_B = 3.2\text{ Adc}$) | $V_{CE(sat)}$ | – – | 1.4 4.0 | Vdc |
| Base-Emitter On Voltage ($I_C = 8\text{ Adc}$, $V_{CE} = 4\text{ Vdc}$) | $V_{BE(on)}$ | – | 2.2 | Vdc |
| DYNAMIC CHARACTERISTICS | | | | |
| Current-Gain – Bandwidth Product ($I_C = 1\text{ Adc}$, $V_{CE} = 10\text{ Vdc}$, $f_{test} = 1\text{ MHz}$) | f_T | 4 | – | MHz |
| Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f_{test} = 1\text{ MHz}$) | C_{ob} | – | 600 | pF |

2. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2\%$.

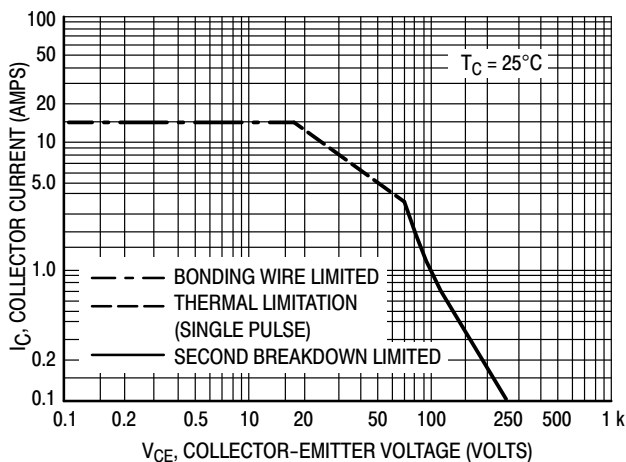


Figure 1. Active-Region Safe Operating Area

There are two limitations on the powerhandling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 1 is based on $T_{J(pk)} = 200^\circ\text{C}$; T_C is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

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TYPICAL CHARACTERISTICS

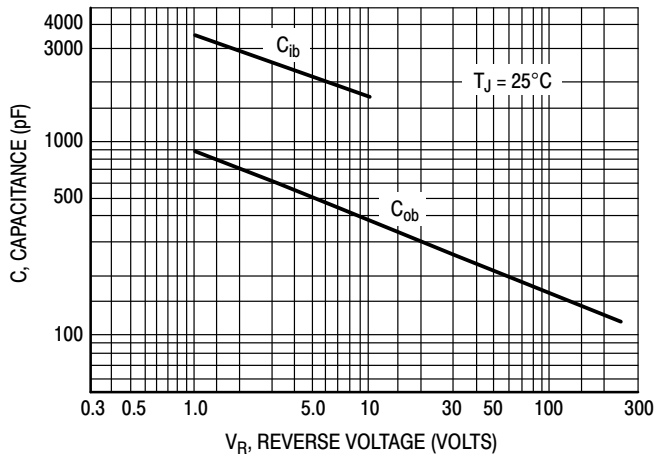


Figure 2. Capacitances

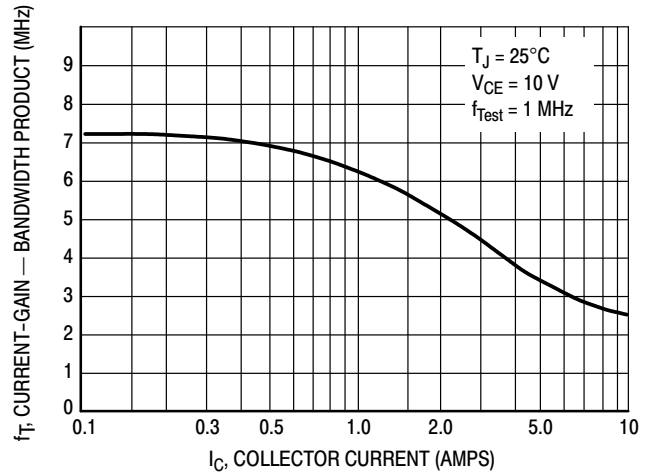


Figure 3. Current-Gain - Bandwidth Product

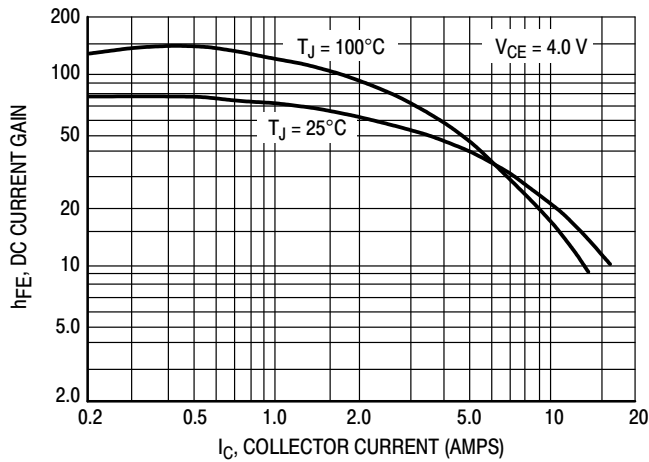


Figure 4. DC Current Gain

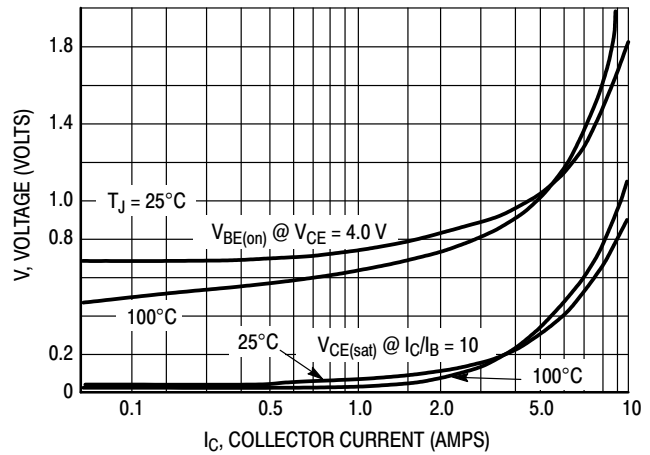
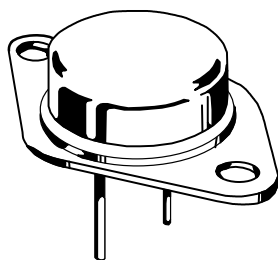


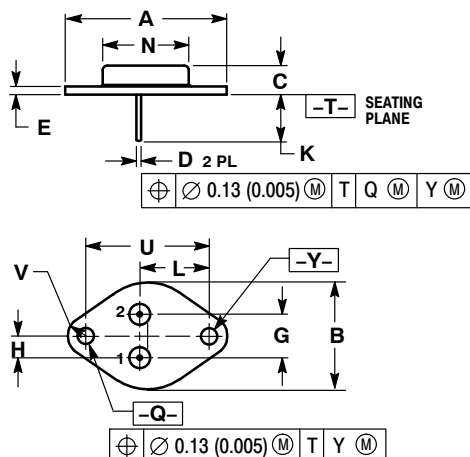
Figure 5. "On" Voltages



TO-204 (TO-3)
CASE 1-07
ISSUE Z

DATE 10 MAR 2000

SCALE 1:1



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

| DIM | INCHES | | MILLIMETERS | |
|-----|-----------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 1.550 REF | | 39.37 REF | |
| B | --- | 1.050 | --- | 26.67 |
| C | 0.250 | 0.335 | 6.35 | 8.51 |
| D | 0.038 | 0.043 | 0.97 | 1.09 |
| E | 0.055 | 0.070 | 1.40 | 1.77 |
| G | 0.430 BSC | | 10.92 BSC | |
| H | 0.215 BSC | | 5.46 BSC | |
| K | 0.440 | 0.480 | 11.18 | 12.19 |
| L | 0.665 BSC | | 16.89 BSC | |
| N | --- | 0.830 | --- | 21.08 |
| Q | 0.151 | 0.165 | 3.84 | 4.19 |
| U | 1.187 BSC | | 30.15 BSC | |
| V | 0.131 | 0.188 | 3.33 | 4.77 |

STYLE 1:
PIN 1. BASE
2. EMITTER
CASE: COLLECTOR

STYLE 2:
PIN 1. BASE
2. COLLECTOR
CASE: EMITTER

STYLE 3:
PIN 1. GATE
2. SOURCE
CASE: DRAIN

STYLE 4:
PIN 1. GROUND
2. INPUT
CASE: OUTPUT

STYLE 5:
PIN 1. CATHODE
2. EXTERNAL TRIP/DELAY
CASE: ANODE

STYLE 6:
PIN 1. GATE
2. EMITTER
CASE: COLLECTOR

STYLE 7:
PIN 1. ANODE
2. OPEN
CASE: CATHODE

STYLE 8:
PIN 1. CATHODE #1
2. CATHODE #2
CASE: ANODE

STYLE 9:
PIN 1. ANODE #1
2. ANODE #2
CASE: CATHODE

| | | |
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